

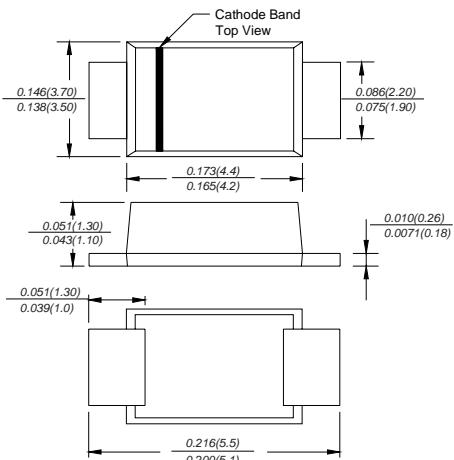


# SS52BF THRU SS520BF

## SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 200 Volts   Forward Current - 5.0 Ampere

### SMBF



Dimensions in inches and (millimeters)

### FEATURES

- ♦ Metal silicon junction, majority carrier conduction
- ♦ For surface mounted applications
- ♦ Low power loss, high efficiency
- ♦ High forward surge current capability
- ♦ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

### MECHANICAL DATA

**Case:** JEDEC SMBF molded plastic body

**Terminals:** leads solderable per MIL-STD-750, Method 2026

**Mounting Position:** Any

**Weight:** 57mg/0.002oz

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

MDD Catalog Number	SYMBOLS	SS52BF	SS54BF	SS56BF	SS58BF	SS510BF	SS515BF	SS520BF	UNITS
Marking code		S52B	S54B	S56B	S58F	S510B	S515B	S520B	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	40	60	80	100	150	200	VOLTS
Maximum RMS voltage	V <sub>RMS</sub>	14	28	42	56	70	105	140	VOLTS
Maximum DC blocking voltage	V <sub>DC</sub>	20	40	60	80	100	150	200	VOLTS
Maximum average forward rectified current at T <sub>L</sub> (see fig.1)	I <sub>(AV)</sub>					5.0			Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>					150.0			Amps
Maximum instantaneous forward voltage at 5.0A	V <sub>F</sub>	0.55	0.70	0.85	0.95				Volts
Maximum DC reverse current T <sub>A</sub> =25°C at rated DC blocking voltage T <sub>A</sub> =100°C	I <sub>R</sub>			1.0					mA
Typical junction capacitance (NOTE 1)	C <sub>J</sub>	800		500					pF
Typical thermal resistance (NOTE 2)	R <sub>θJA</sub>			40.0					°C/W
Operating junction temperature range	T <sub>J</sub>			-50 to +125					°C
Storage temperature range	T <sub>STG</sub>			-50 to +150					°C

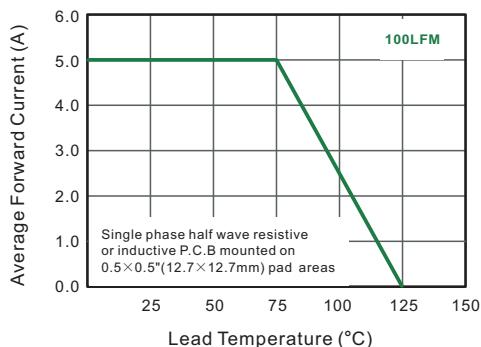
**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

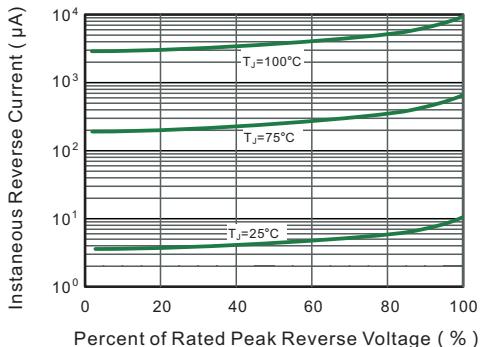


# RATINGS AND CHARACTERISTIC CURVES SS52BF THRU SS520BF

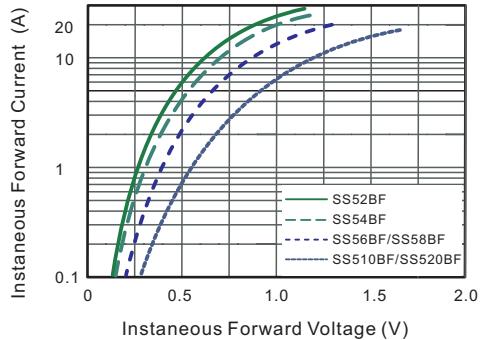
**Fig.1 Forward Current Derating Curve**



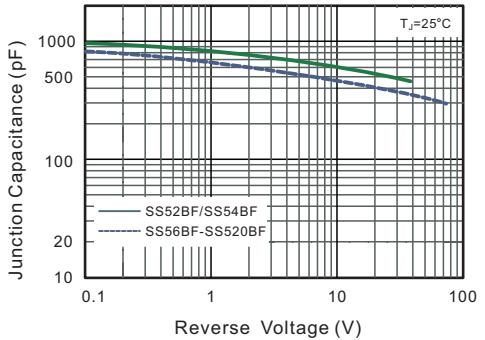
**Fig.2 Typical Reverse Characteristics**



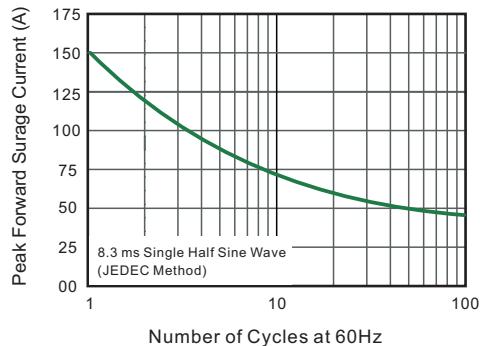
**Fig.3 Typical Forward Characteristic**



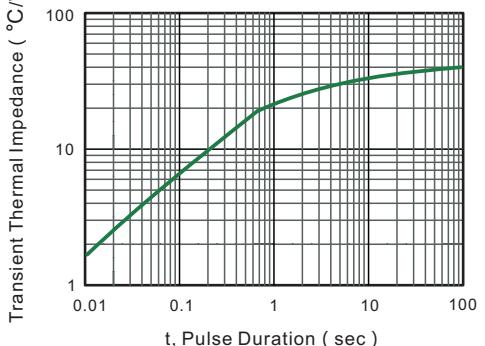
**Fig.4 Typical Junction Capacitance**



**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



**Fig.6- Typical Transient Thermal Impedance**



The curve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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